勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

# 

# **Quad SPDT CMOS Analog Switch**

#### **General Description**

The MAX333 is a quad single-pole-double-throw (SPDT) analog switch. These four independent switches can be operated with bipolar power supplies ranging from ±5V to ±18V, or single-ended power supplies of +10V to +30V.

The MAX333 has break-before-make switching, (200ns typical), a maximum turn-off time of 500ns, and a maximum turn-on time of 1000ns.

The MAX333 is ideal for portable operation since quiescent current is only  $250\mu\text{A}$  maximum with all inputs high, and less with all inputs low.

Logic inputs are fully TTL and CMOS compatible and guaranteed over a +0.8V to +2.4V range, regardless of supply voltage. Logic inputs and switched analog signals can range anywhere between the supply voltages without damage. The MAX333 is a low-cost replacement for a DG211/DG212 pair when used as a quad SPDT switch.

#### **Applications**

Winchester Disk Drives

Test Equipment

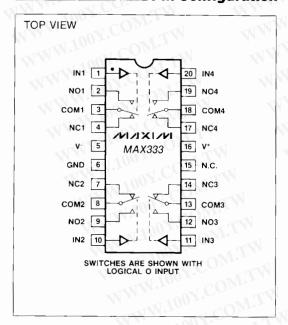
Communications Systems

PBX, PABX

Head up Displays

Portable Instruments

### Pin Configuration



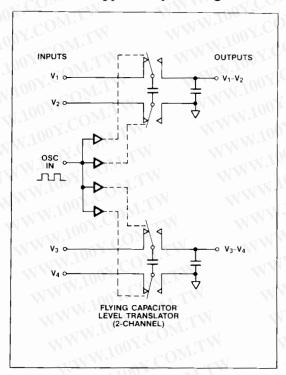
#### **Features**

- **♦ Low Cost Per Channel**
- ♦ Four Independent SPDT Switches
- Break-Before-Make Switching
- ♦ Guaranteed ±5V to ±18V Operation
- Guaranteed +10V to +30V Operation (Single Supply)
- ♦ No Separate Logic Supply Required
- ♦ CMOS and TTL Logic Compatible
- ♦ Monolithic, Low Power CMOS Design

### Ordering Information

PART	TEMP. RANGE	PACKAGE				
MAX333CPP	0°C to +70°C	20 Lead Plastic DIP				
MAX333C/D	0°C to +70°C	Dice				
MAX333EPP	-40°C to +85°C	20 Lead Plastic DIP				
MAX333MJP	-55°C to +125°C	20 Lead CERDIP				
MAX333CWP	0°C to +70°C	20 Lead Wide SO				
MAX333EWP	-40°C to +85°C	20 Lead Wide SO				

### **Typical Operating Circuit**



MIXIM

Maxim Integrated Products 1

Call toll free 1-800-998-8800 for free samples or literature.

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# **Quad SPDT CMOS Analog Switch**

#### ABSOLUTE MAXIMUM RATINGS

V to V	
V <sub>IN</sub> , V <sub>COM</sub> , V <sub>NO</sub> or V <sub>NC</sub>	√ to V
V <sub>NO</sub> - V <sub>NO</sub>	32V
V* to Ground	30V
V⁻ to Ground	30V
Current, Any Terminal Except VCOM, VNO, or VNC	30mA
Continuous Current, VCOM, VNO or VNC	20mA
Peak Current, V <sub>COM</sub> , V <sub>NO</sub> or V <sub>NC</sub>	
(Pulsed at 1msec, 10% duty cycle max)	70mA

Storage Temperature ... -65°C to +150°C Power Dissipation (Note 1) 20 Pin CERDIP (Note 2)
20 Pin Plastic DIP (Note 3) 20 Pin Small Outline (WE) (Note 4) ...... Note 1: Device mounted with all leads soldered to PC board.

Note 2: Derate 11.1mW/°C above 70°C.

Note 3: Derate 8mW/°C above 70°C. Note 4: Derate 10mW/°C above 70°C

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

(GND = 0V,  $V^+$  = +15V,  $V^-$  = -15V,  $T_A$  = +25°C, unless otherwise indicated)

	W			Mi		
PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 5)	TYP (Note 6)	MAX	UNITS
SUPPLY	MAN	1007:001		- 11	001.	Mo
Positive Supply Current	L	W. S. COL		0.13	0.25	mA
Supply Voltage Range	V*/V-	Dual Supply;  V*  =  V-	±5	TO THE STATE OF TH	±18	V
Supply Voltage Range	V <sup>+</sup>	Single Supply; V = GND	+10	1111	+30	V
Negative Supply Current	I <sup>-</sup>	TWN OV. CO.		0.01	0.25	mA
LOGIC INPUT		11N.100 COM. 1	_1	- 757	M'In	-7 C
Input Voltage Low	V <sub>IL</sub>	NN TIOOLO TAT	V-		+0.8	V
Input Voltage High	V <sub>IH</sub>	MMM.	2.4		V <sup>+</sup>	V
Input Current	I <sub>IN</sub>	$V_{1N} = V^-, V^+$	-10	0.0001	+10	μΑ
SWITCH		M = 100x	11/1		-47	1007
Analog Signal Range	V <sub>ANA</sub>	M.M. O.Y.CO.	V		V <sup>+</sup>	V
ON Circuit Resistance	R <sub>ON</sub>	V <sub>ANA</sub> = +10V; I <sub>COM</sub> = 1mA V <sub>ANA</sub> = -10V; I <sub>COM</sub> = 1mA	TW	140 125	175 175	Ω
ON Circuit Leakage Current	IONL	V <sub>ANA</sub> = +14V; V <sub>OFF</sub> = -14V V <sub>ANA</sub> = -14V; V <sub>OFF</sub> = +14V	-5 -5	0.1 0.2	+5	nA nA
OFF Circuit Leakage Current	I <sub>OFF</sub>	V <sub>ANA</sub> = +14V; V <sub>OFF</sub> = -14V V <sub>ANA</sub> = -14V; V <sub>OFF</sub> = +14V	-5 -5	0.01 0.02	+5 +5	nA nA
DYNAMIC	TV	WW.				
Turn-off Time	t <sub>OFF</sub>	(See Switching Time Test Circuit)	$CO_{Mr}$	50	500	ns
Turn-on Time	ton	100		460	1000	ns
Break-before-make Time	topen	W WW LOO	50	200		ns
Off Capacitance	C <sub>OFF</sub>	V <sub>ANA</sub> = 0V	ST CO	5		pF
On Capacitance	C <sub>ON</sub>	V <sub>ANA</sub> = 0V	O.E.	5		pF
Off Isolation	OIRR	f = 1MHz, RI = 75Ω V <sub>ANA</sub> = 2.3V <sub>RMS</sub>	00 X.C.	72	N	dB
Crosstalk	CCRR	TIN TO	100 X.	78		dB

The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used

Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

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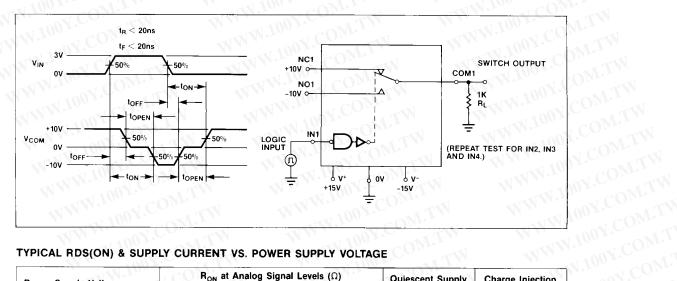
# **Quad SPDT CMOS Analog Switch**

#### **ELECTRICAL CHARACTERISTICS**

(GND = 0V, V' = +15V, V' = -15V, T<sub>A</sub> = Full Operating Temperature Range, unless otherwise indicated)

PARAMETER	···C	Ohr MM.	100			
	SYMBOL	TEST CONDITIONS	MIN (Note 5)	TYP (Note 6)	MAX	UNITS
LOGIC INPUT	M.Ing	CONT	MW.IV	~ 1 CO		- I
Input Voltage Low	V <sub>IL</sub>	. M.T.	V- 1	10 7	+0.8	V
Input Voltage High	V <sub>IH</sub>	V.Co. CAN N	2.4	OUN.	ν.	V
Input Current	I <sub>IN</sub>	V <sub>IN</sub> = V <sup>-</sup> , V <sup>+</sup>	-10	0.0001	+10	μΑ
SWITCH	-110	O. W.I.A.	11	1100	MOD	
Analog Signal Range	V <sub>ANA</sub>	OUX.CO. TW	V-	1007	V'	V
ON Circuit Resistance	R <sub>ON</sub>	V <sub>ANA</sub> = +10V; I <sub>COM</sub> = 1mA V <sub>ANA</sub> = -10V; I <sub>COM</sub> = 1mA	WW	200 180	250 250	Ω
ON Circuit Leakage Current	I <sub>ONL</sub>	V <sub>ANA</sub> = +15V; V <sub>OFF</sub> = -15V V <sub>ANA</sub> = -15V; V <sub>OFF</sub> = +15V	WV	200 200	OY.Co	nA nA
OFF Circuit Leakage Current	I <sub>OFF</sub>	V <sub>ANA</sub> = +15V; V <sub>OFF</sub> = -15V V <sub>ANA</sub> = -15V; V <sub>OFF</sub> = +15V	W	100 100	00 Y.C	nA nA

### Switching Time Test Circuit



#### TYPICAL RDS(ON) & SUPPLY CURRENT VS. POWER SUPPLY VOLTAGE

Power Supply Voltage	R <sub>ON</sub> at Analog Signal Levels (Ω)								
Power Supply Voltage	-15V	-10V	-5V	0V	+5V	+10V	+15V	Quiescent Supply Current (μA)	Charge Injection (pC)
$V^- = -15V, V^+ = +15V$	117			109	1	MAA	153	130	12
$V^{-} = -10V, V^{+} = +10V$	~ 1	158		156		171	Mis	80	10
V = -5V, V* = +5V	00 2.		297	303	288	44	W.	30	8
V- = GND, V+ = +15V	.003		_ 1 7	200			212	115	$\mathcal{I}_M$
V" = GND, V" = +10V	Too	et C	Mr.	300	312	303	WV	30	

# **Quad SPDT CMOS Analog Switch**

#### **ELECTRICAL CHARACTERISTICS (Single Supply)**

(GND = 0V, V' = +12V, V' = 0V,  $T_A = 25^{\circ}$ C, unless otherwise indicated)

	1007.	MIN	1100 1	LIMITS		UNITS
PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 5)	TYP (Note 6)	MAX	
SUPPLY	Looy!	CO TIN WY	-110	17.0	VIII	_
Supply Voltage Range	V*	Single Supply; V <sup>-</sup> = GND	+10	ON CO	+30	V
Positive Supply Current	100	COM:	TW.1	0.11	0.25	mA
INPUT	100	Y.C. TIN W	71	1007.	~117	
Input Voltage Low	V <sub>INLO</sub>	CONT	0	oov.	+0.8	V
Input Voltage High	V <sub>INHI</sub>	ON'I	2.4	1.700	_ V'	V
Input Current	I <sub>IN</sub>	V <sub>IN</sub> = V', OV	1/1/1/	-1100 X	1	μΑ
SWITCH		CONT		M.,	V.CO	
Analog Signal Range	VANA	Jon COM'T	V-	11.100	V <sup>+</sup>	Tv
ON Circuit Resistance	R <sub>ON</sub>	V <sub>ANA</sub> = +10V; I <sub>COM</sub> = 1mA V <sub>ANA</sub> = 0V; I <sub>COM</sub> = 1mA		250 240	350 350	Ω
ON Circuit Leakage Current	I <sub>ONL</sub>	$V_{ANA} = V^*; V_{OFF} = 0V$ $V_{ANA} = 0V; V_{OFF} = V^*$		0.05 0.05	007.	nA nA
OFF Circuit Leakage Current	I <sub>OFF</sub>	$V_{ANA} = V^+$ $V_{ANA} = 0V$		0.01 0.01	700	nA nA
DYNAMIC		TW. Ion COM.		-111	1.700	7 CO
Turn-off Time	t <sub>OFF</sub>	(See Switching Time Test Circuit)		65	x 100	ns
Turn-on Time	t <sub>ON</sub>	MININO ON COPY	N	700	44.	ns
Break-before-make Time	t <sub>OPEN</sub>	CON.		200	W.10	ns
Off Isolation	OIRR	f = 1MHz, RI = 75Ω V <sub>ANA</sub> = 2.3V <sub>RMS</sub>	-XX	70	WW.1	dB
Crosstalk	CCRR	M 100 - OM		72	TXN	dB

Note 5: The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this data sheet.

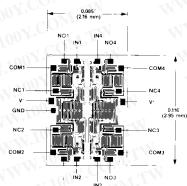
Note 6: Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

# Protecting Against \_\_\_Fault Conditions

Fault conditions occur when power supplies are turned off when input signals are still present or when over voltages occur at the inputs during normal operation. In either case, source-to-body diodes can be forward biased and conduct current from the signal source. If this current is required to be kept to low ( $\mu$ A) levels then the addition of external protection diodes is recommended.

To provide protection for over-voltages up to 20V above the supplies, 1N4001 or 1N914 type diodes should be placed in series with the positive and negative supplies. The addition of these diodes will reduce the analog signal range to 1 volt below the positive supply and 1 volt above the negative supply.

## Chip Topography



NOTE: NCx IS CONNECTED TO COMx WHEN INX IS LOW.

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